VISHAY

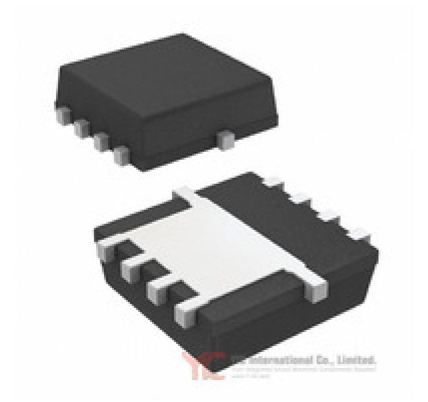


Image may be representation.
See specs for product details.

SIS424DN-T1-GE3

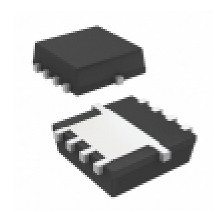
Hersteller-Teilenummer:	SIS424DN-T1-GE3
Hersteller / Marke:	Vishay / Siliconix
Teil der Beschreibung:	MOSFET N-CH 20V 35A PPAK 1212-8
Datenblätter:	SIS424DN-T1-GE3.pdf
RoHs Status:	Bleifrei / RoHS-konform
Lagerzustand:	New original, 16505 pcs Stock Available.
Liefern von:	Hong Kong
Versandweg:	DHL/Fedex/TNT/UPS/EMS

Spezifikationen

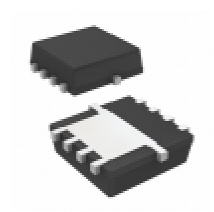
Teilenummer	SIS424DN-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 20V 35A PPAK 1212-8
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	16505 pcs Stock
VGS (th) (Max) @ Id	2.5V @ 250µA
Technologie	MOSFET (Metal Oxide)
Supplier Device-Gehäuse	PowerPAK® 1212-8
Serie	TrenchFET®
Rds On (Max) @ Id, Vgs	6.4 mOhm @ 19.6A, 10V
Verlustleistung (max)	3.7W (Ta), 39W (Tc)
Verpackung	Tape & Reel (TR)
Verpackung / Gehäuse	PowerPAK® 1212-8
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Eingabekapazität (Ciss) (Max) @ Vds	1200pF @ 10V
Gate Charge (Qg) (Max) @ Vgs	30nC @ 10V
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	35A (Tc)

SIS424DN-T1-GE3 Electronic Components ist ein 100% neues Original von YIC Distributor, SIS424DN-T1-GE3-Datenblätter durchsuchen, PDF, Inventar bei Y-IC.com Online, SIS424DN-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen bestellen. Versand per DHL / FedEx / TNT / UPS Express. Unterstützung der Zahlung mit telegrafischer Überweisung (T / T) oder PayPal. RFQ SIS424DN-T1-GE3 E-Mail: Info@Y-IC.com

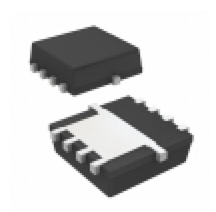
Sie können auch interessiert sein:



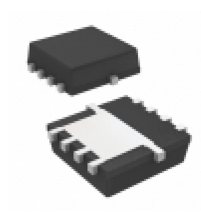
SIS415DNT-T1-GE3
Electro-Films (EFI) / Vishay
MOSFET P-CH 20V 35A 1212-8



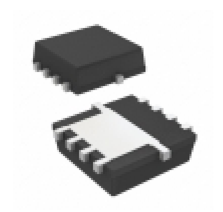
SIS426DN-T1-GE3
Electro-Films (EFI) / Vishay
MOSFET N-CH 20V 35A 1212-8



SIS426DN-T1-GE3
Vishay Siliconix
MOSFET N-CH 20V 35A 1212-8



SIS414DN-T1-GE3
Electro-Films (EFI) / Vishay
MOSFET N-CH 30V 20A 1212-8 PPAK



SIS424DN-T1-GE3
Electro-Films (EFI) / Vishay
MOSFET N-CH 20V 35A PPAK 1212-8

Not Actual Photo
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SIS424DN
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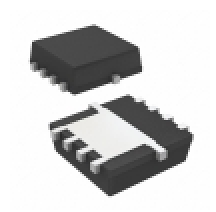
SIS424DN VB



SIS415DNT-T1-GE3
Vishay Siliconix
MOSFET P-CH 20V 35A 1212-8

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SIS426DN-T1-E3
VISHAY
SIS426DN-T1-E3 VISHAY

SIS424DN-T1-GE3 Zugehöriges Schlüsselwort

Mehr

SIS424DN-T1-GE3 Vishay / Siliconix
SIS424DN-T1-GE3 Datenblatt
SIS424DN-T1-GE3-Datenblätter
SIS424DN-T1-GE3 PDF
Vishay / Siliconix SIS424DN-T1-GE3
SIS424DN-T1-GE3 Electronic
SIS424DN-T1-GE3-Komponenten
SIS424DN-T1-GE3-Verteiler
SIS424DN-T1-GE3-Bild
SIS424DN-T1-GE3-Teil
SIS424DN-T1-GE3 Preis
SIS424DN-T1-GE3 Hersteller
SIS424DN-T1-GE3 Bild
SIS424DN-T1-GE3 Aktie
SIS424DN-T1-GE3 Inventar
SIS424DN-T1-GE3 Neu
SIS424DN-T1-GE3 Original
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